



High Current Density Surface Mount Schottky Barrier Rectifiers



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5.0 A
V_{RRM}	30 V, 40 V
I_{FSM}	200 A
E_{AS}	20 mJ
V_F at $I_F = 5$ A	0.37 V
T_J max.	150 °C

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- **Halogen-free according to IEC 61249-2-21 definition**

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)				
PARAMETER	SYMBOL	SS10P3C	SS10P4C	UNIT
Device marking code		S103C	S104C	
Maximum repetitive peak reverse voltage	V_{RRM}	30	40	V
Maximum average forward rectified current (fig. 1) total device per diode	$I_{F(AV)}$	10 5.0		A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	200		A
Non-repetitive avalanche energy at 25 °C, $I_{AS} = 2$ A per diode	E_{AS}	20		mJ
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150		°C

SS10P3C, SS10P4C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 2.5 A	T _A = 25 °C	V _F	0.40	-	V
	I _F = 5.0 A			0.45	0.53	
	I _F = 2.5 A	T _A = 125 °C		0.29	-	
	I _F = 5.0 A			0.37	0.44	
Reverse current per diode ⁽²⁾	Rated V _R	T _A = 25 °C T _A = 125 °C	I _R	56 28	550 45	μA mA
Typical junction capacitance per diode	4.0 V, 1 MHz		C _J	430	-	pF

Notes⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SS10P3C	SS10P4C	UNIT
Typical thermal resistance per diode	R _{θJA} ⁽¹⁾	60		°C/W
	R _{θJL}	3		

Note⁽¹⁾ Units mounted on recommended P.C.B. 1 oz. pad layout

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS10P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS10P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS10P4CHM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS10P4CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note⁽¹⁾ Automotive grade



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

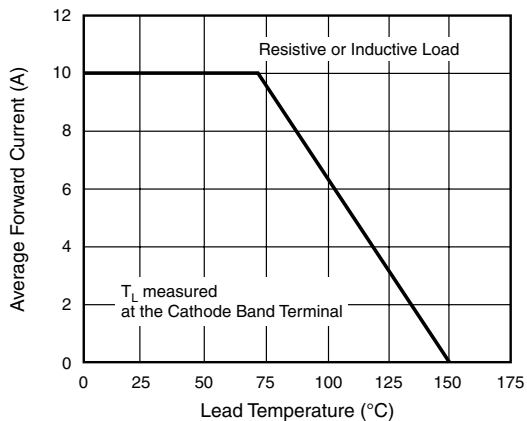


Figure 1. Maximum Forward Current Derating Curve

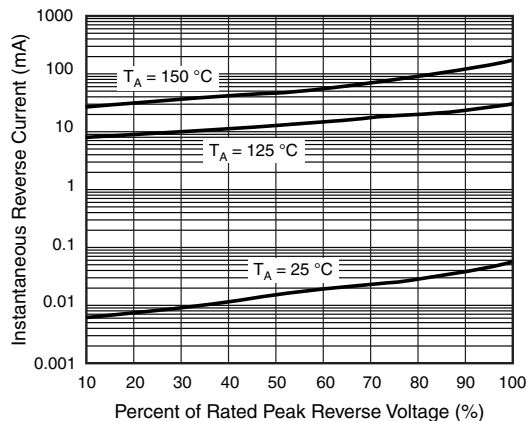


Figure 4. Typical Reverse Leakage Characteristics Per Diode

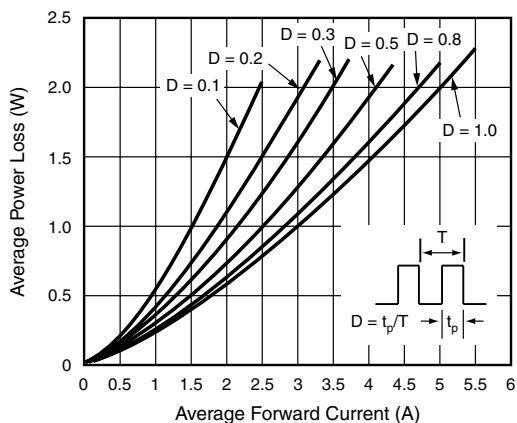


Figure 2. Forward Power Loss Characteristics Per Diode

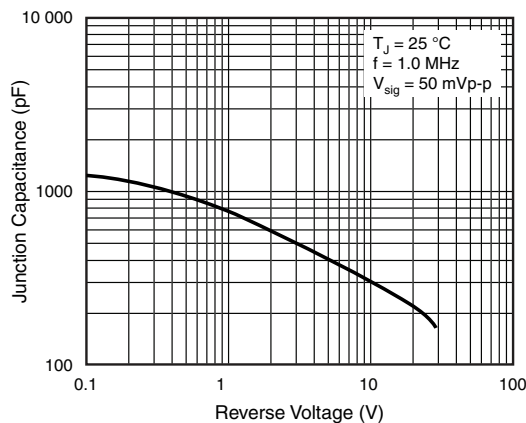


Figure 5. Typical Junction Capacitance Per Diode

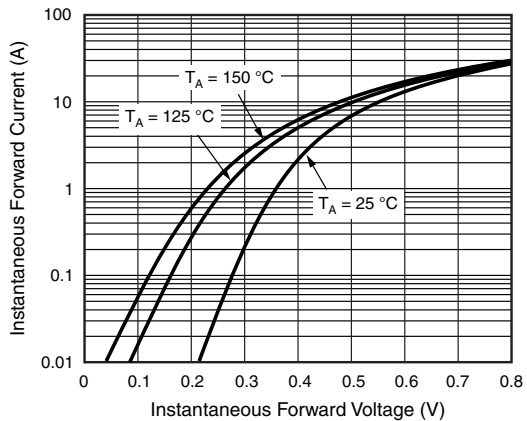


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

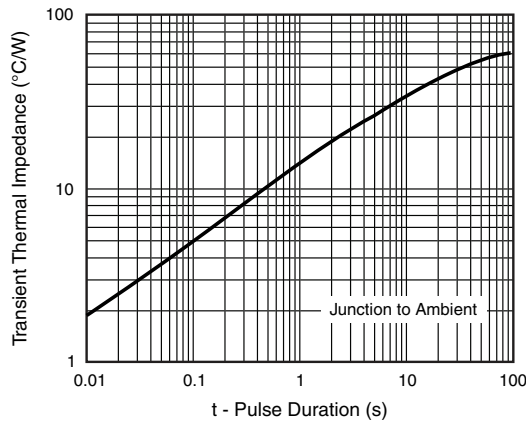


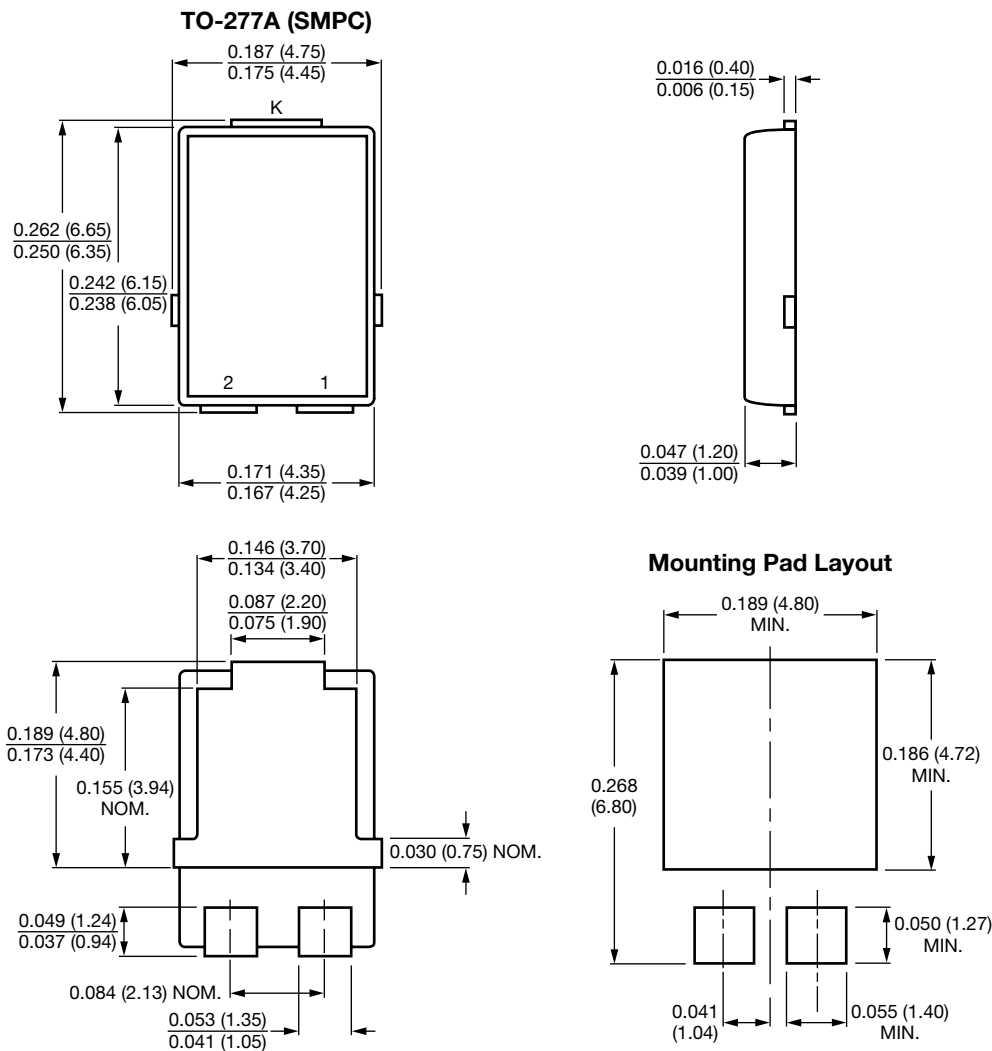
Figure 6. Typical Transient Thermal Impedance Per Diode

SS10P3C, SS10P4C

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Conform to JEDEC TO-277A



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